



DMN6010SCTBQ

# **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(on)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
60V	10mΩ @ V <sub>GS</sub> = 10V	128A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Motor Controls
- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

# Features and Benefits

 100% Unclamped Inductive Switching (UIS) Test in Production – Ensures More Reliable and Robust End Application

**60V N-CHANNEL ENHANCEMENT MODE MOSFET** 

- Low RDS(on) Minimizes Power Losses
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN6010SCTBQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

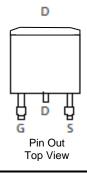
# **Mechanical Data**

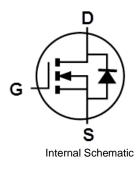
- Package: TO263AB
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 1.7 grams (Approximate)



TO263AB (D2PAK)

Top View





## Ordering Information (Note 4)

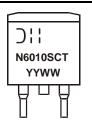
Part Number	Package	Packing		
Fart Nulliber	Гаскауе	Qty.	Carrier	
DMN6010SCTBQ-13	TO263AB (D2PAK)	800	Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



] | = Manufacturer's Marking
 N6010SCT = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 21 = 2021)
 WW = Week (01 to 53)



# Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage	Vgss	±20	V	
	Tc = +25°C		128	
Continuous Drain Current (Note 6) VGS = 10V	Tc = +70°C	ID	102	A
Maximum Continuous Body Diode Forward Current (Note 6)	Tc = +25°C	ls	128	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	512	A	
Avalanche Current, L =0.1mH	las	71	A	
Avalanche Energy, L = 0.1mH		Eas	252	mJ

# Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	5	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	30	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	312	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.4	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

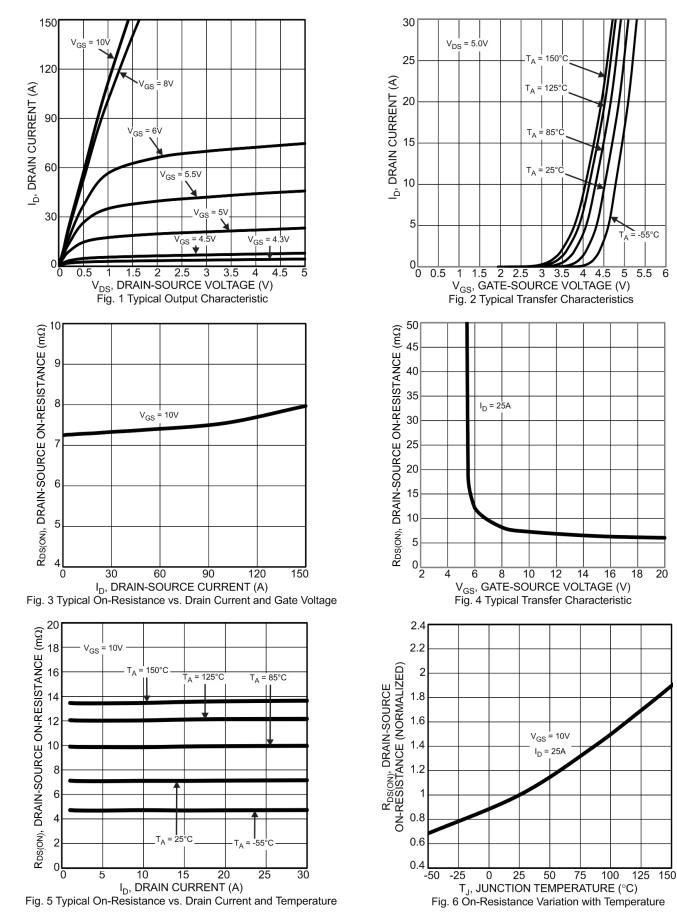
### Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)					•	•	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	10	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss	_	_	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	2	_	4	V	$V_{DS} = V_{GS}, I_D = 1mA$	
Static Drain-Source On-Resistance	RDS(on)	_	7.7	10	mΩ	VGS = 10V, ID = 25A	
Diode Forward Voltage	V <sub>SD</sub>	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 25A$	
DYNAMIC CHARACTERISTICS (Note 8)	· · ·						
Input Capacitance	Ciss	—	2692				
Output Capacitance	Coss	_	909	_	pF	V <sub>DS</sub> =25V, V <sub>GS</sub> = 0V f = 1MHz	
Reverse Transfer Capacitance	Crss	_	65	_			
Gate Resistance	Rg	_	3.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	46	_			
Gate-Source Charge	Qgs	_	12	_	nC	V <sub>DS</sub> = 44V, I <sub>D</sub> = 25A, V <sub>GS</sub> = 10V	
Gate-Drain Charge	Q <sub>gd</sub>	_	13	_			
Turn-On Delay Time	tD(on)		13.5	_			
Turn-On Rise Time	tR	—	44		ns	$\label{eq:VDS} \begin{split} V_{DS} &= 30V,  V_{GEN} = 10V, \\ R_L &= 1.2\Omega \end{split}$	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	45	_			
Turn-Off Fall Time	tF	_	29	_	1		
Reverse Recovery Time	t <sub>RR</sub>	_	51.5	—	ns	I <sub>F</sub> = 20A, di/dt = 100A/μs,	
Reverse Recovery Charge	Q <sub>RR</sub>		92	_	nC	$V_R = 30V$	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.
6. Thermal resistance from junction to soldering point (on the exposed drain pad).
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing. Notes:

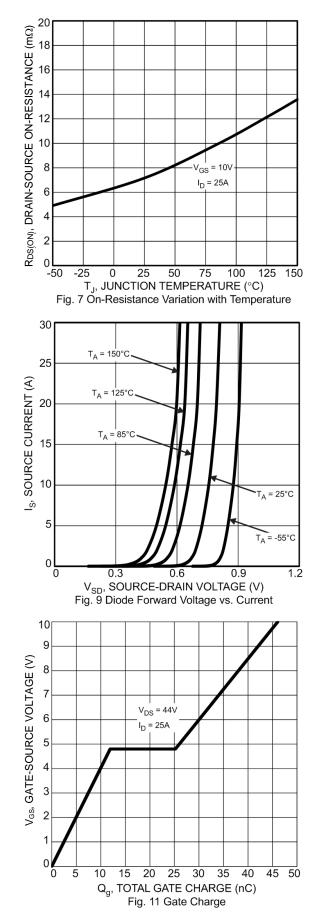


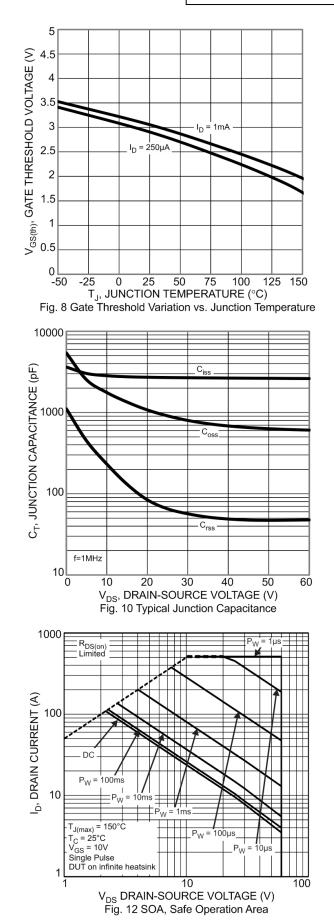
# DMN6010SCTBQ



DMN6010SCTBQ Document number: DS43783 Rev. 2 - 2

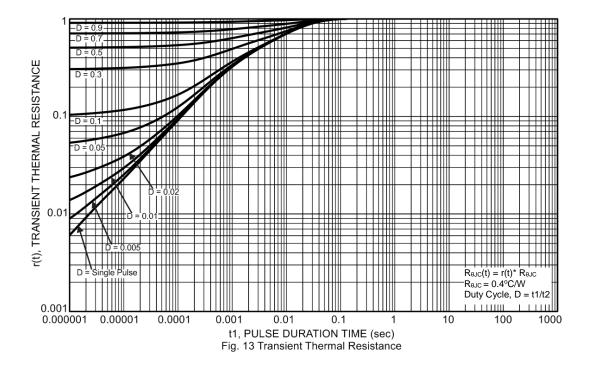






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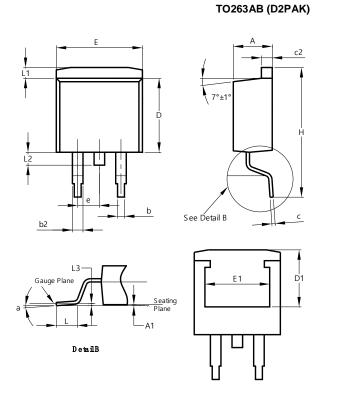






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

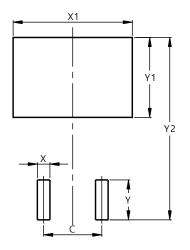


TO	TO263AB (D2PAK)				
Dim	Min	Max	Тур		
Α	4.07	4.82	-		
A1	0.00	0.25	-		
b	0.51	0.99	-		
b2	1.15	1.77	-		
С	0.356	0.73	-		
c2	1.143	1.65	-		
D	8.39	9.65	-		
D1	6.55	6.95	-		
е	:	2.54 TYP			
Е	9.66	10.66	-		
E1	6.23	8.23	-		
Н	14.61	15.87	-		
L	1.78	2.79	-		
L1	-	1.67	-		
L2	-	1.77	-		
L3	-	-	0.254		
а	0°	8°	-		
All D	All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO263AB (D2PAK)



Dimensions	Value (in mm)			
С	5.08			
Х	1.10			
X1	10.41			
Y	3.50			
Y1	7.01			
Y2	15.99			



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